



Standard Recovery Diodes (Stud Version), 380 A



DO-205AB (DO-9)

FEATURES

- Wide current range
- High voltage ratings up to 3200 V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC® types
- Compression bonded encapsulations
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

PRODUCT SUMMARY

$I_{F(AV)}$	380 A
Package	DO-205AB (DO-9)
Circuit configuration	Single diode

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VS-SD300N/R		UNITS
		16 to 20	25 to 32	
$I_{F(AV)}$		380	380	A
	T_C	100	70	°C
$I_{F(RMS)}$		595	425	A
I_{FSM}	50 Hz	6050	6050	
	60 Hz	6335	6335	
I^2t	50 Hz	183	183	kA ² s
	60 Hz	167	167	
V_{RRM}	Range	1600 to 2000	2500 to 3200	V
T_J		- 40 to 180	- 40 to 150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
VS-SD300N/R	16	1600	1700	15
	20	2000	2100	
	25	2500	2600	
	28	2800	2900	
	32	3200	3300	



FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		SD300N/R		UNITS
				16 to 20	25 to 32	
Maximum average forward current at case temperature	$I_{F(AV)}$	180° conduction, half sine wave		380	270	A
				100	100	°C
				300	380	A
				125	70	°C
Maximum RMS forward current	$I_{F(RMS)}$	DC at $T_C = 88\text{ °C}$ (02 to 24), $T_C = 91\text{ °C}$ (25 to 32)		595	425	A
Maximum peak, one-cycle forward, non-repetitive surge current	I_{FSM}	t = 10 ms	No voltage reappplied	6050		
		t = 8.3 ms		6335		
		t = 10 ms	100 % V_{RRM} reappplied	5090		
		t = 8.3 ms		5330		
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reappplied	183		
		t = 8.3 ms		167		
		t = 10 ms	100 % V_{RRM} reappplied	129		
		t = 8.3 ms		118		
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reappplied		1830	$kA^2\sqrt{s}$	
Low level value of threshold voltage	$V_{F(TO)1}$	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.95	V	
High level value of threshold voltage	$V_{F(TO)2}$	$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		1.05		
Low level value of forward slope resistance	r_{f1}	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.75	$m\Omega$	
High level value of forward slope resistance	r_{f2}	$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.66		
Maximum forward voltage drop	V_{FM}	$I_{pk} = 1180\text{ A}$, $T_J = T_J$ maximum, $t_p = 10\text{ ms}$ sinusoidal wave		1.83	1.83	V

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		SD300N/R		UNITS
				16 to 20	25 to 32	
Maximum junction operating temperature range	T_J			-40 to 180	-40 to 150	°C
Maximum storage temperature range	T_{Stg}			-55 to 200		
Maximum thermal resistance, junction to case	R_{thJC}	DC operation		0.11		K/W
Maximum thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth, flat and greased		0.04		
Maximum allowed mounting torque $\pm 10\%$		Not-lubricated threads		27		Nm
Approximate weight				250		g
Case style		See dimensions (link at the end of datasheet)		DO-205AB (DO-9)		



ΔR_{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.019	0.013	T _J = T _J maximum	K/W
120°	0.023	0.023		
90°	0.028	0.030		
60°	0.042	0.044		
30°	0.073	0.074		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

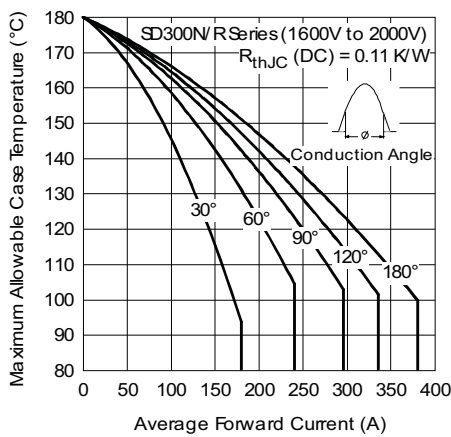


Fig. 1 - Current Ratings Characteristics

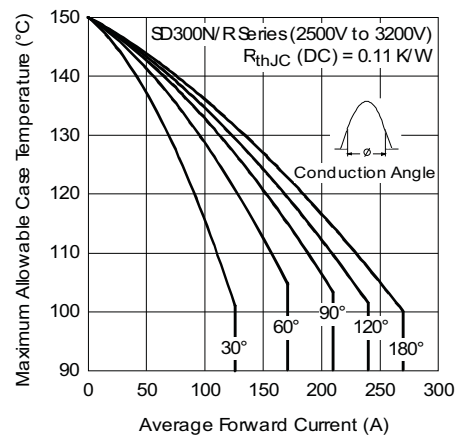


Fig. 3 - Current Ratings Characteristics

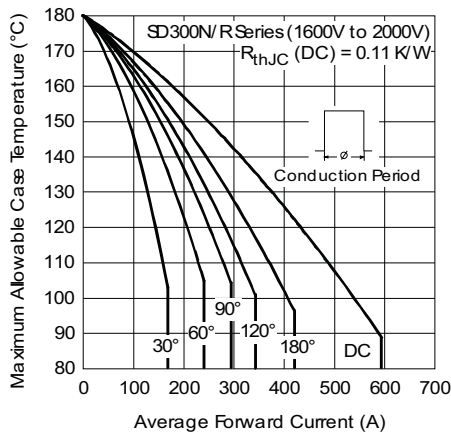


Fig. 2 - Current Ratings Characteristics

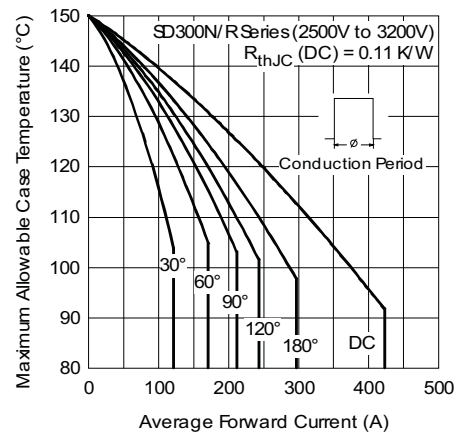


Fig. 4 - Current Ratings Characteristics

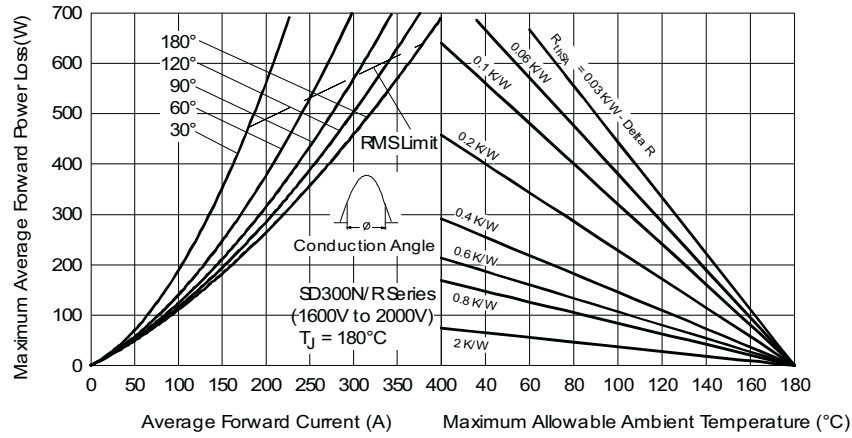


Fig. 5 - Forward Power Loss Characteristics

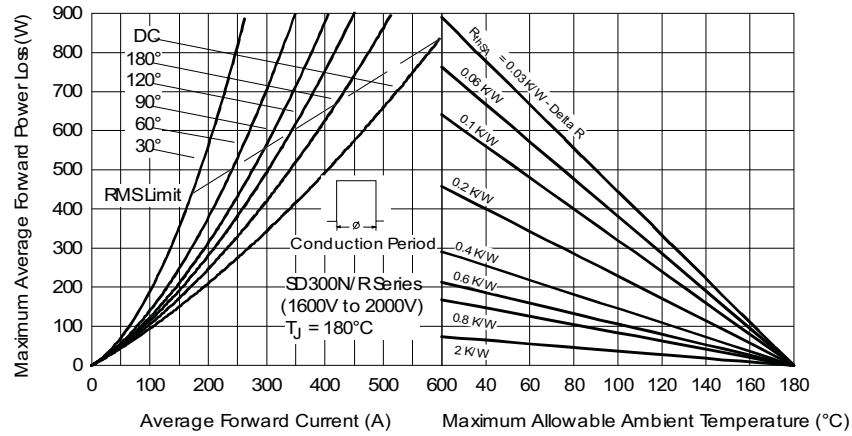


Fig. 6 - Forward Power Loss Characteristics

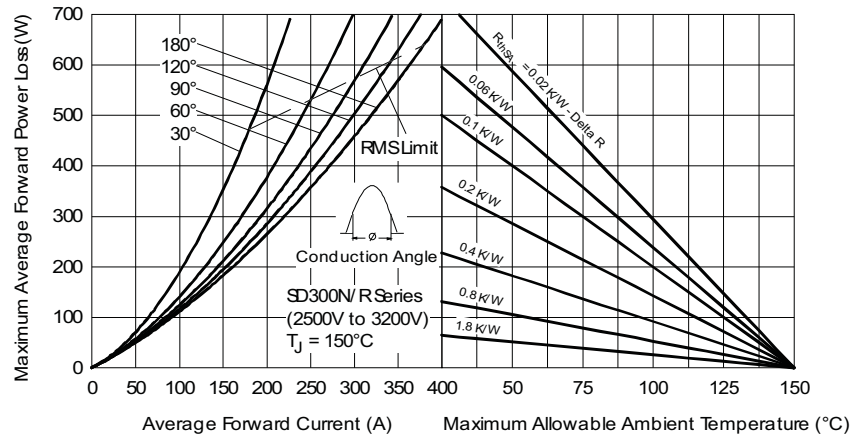


Fig. 7 - Forward Power Loss Characteristics

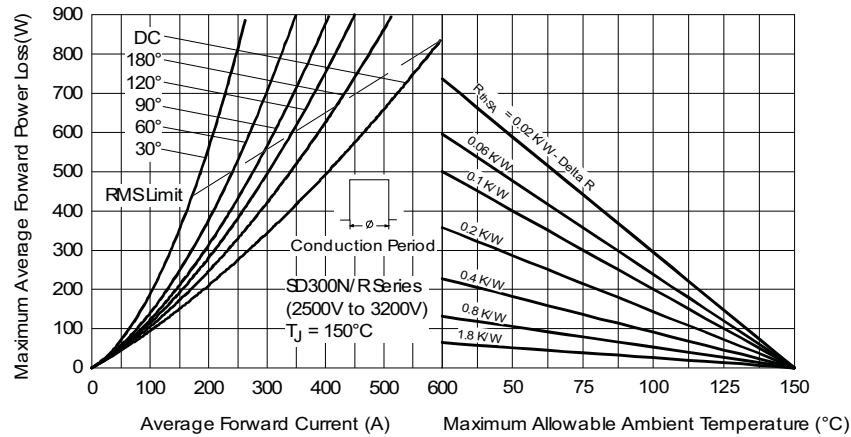


Fig. 8 - Forward Power Loss Characteristics

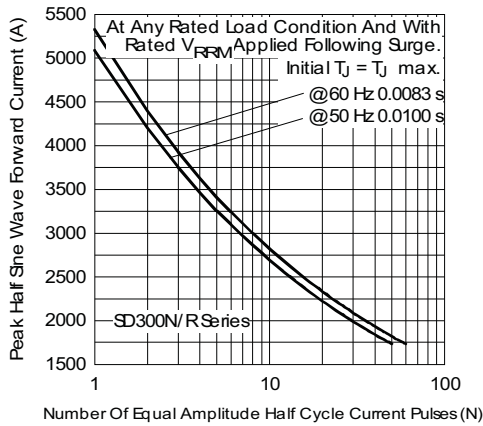


Fig. 9 - Maximum Non-Repetitive Surge Current

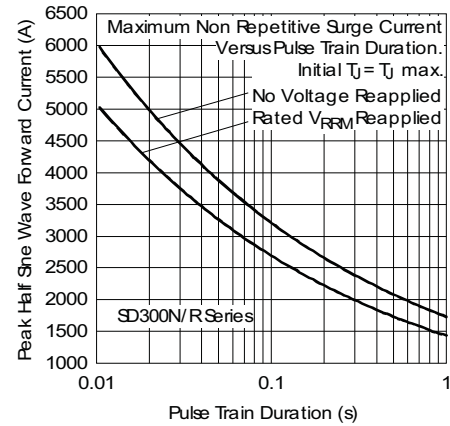


Fig. 10 - Maximum Non-Repetitive Surge Current

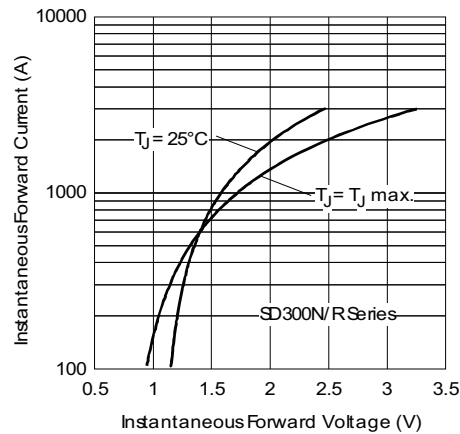


Fig. 11 - Forward Voltage Drop Characteristics

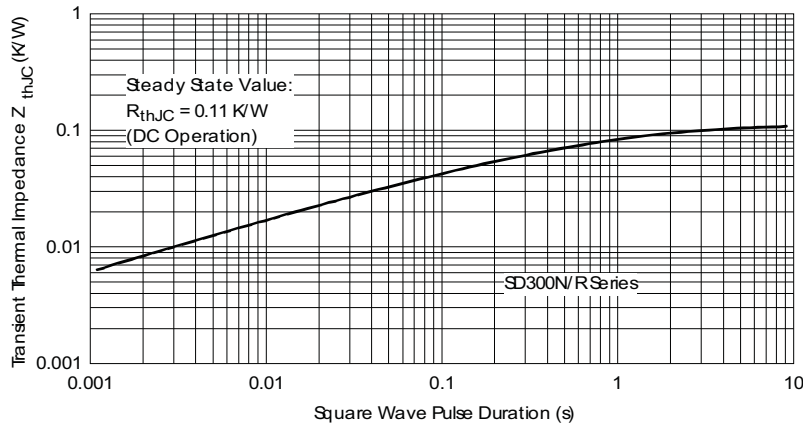


Fig. 12 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code	VS-	SD	30	0	N	32	P	C
	①	②	③	④	⑤	⑥	⑦	⑧

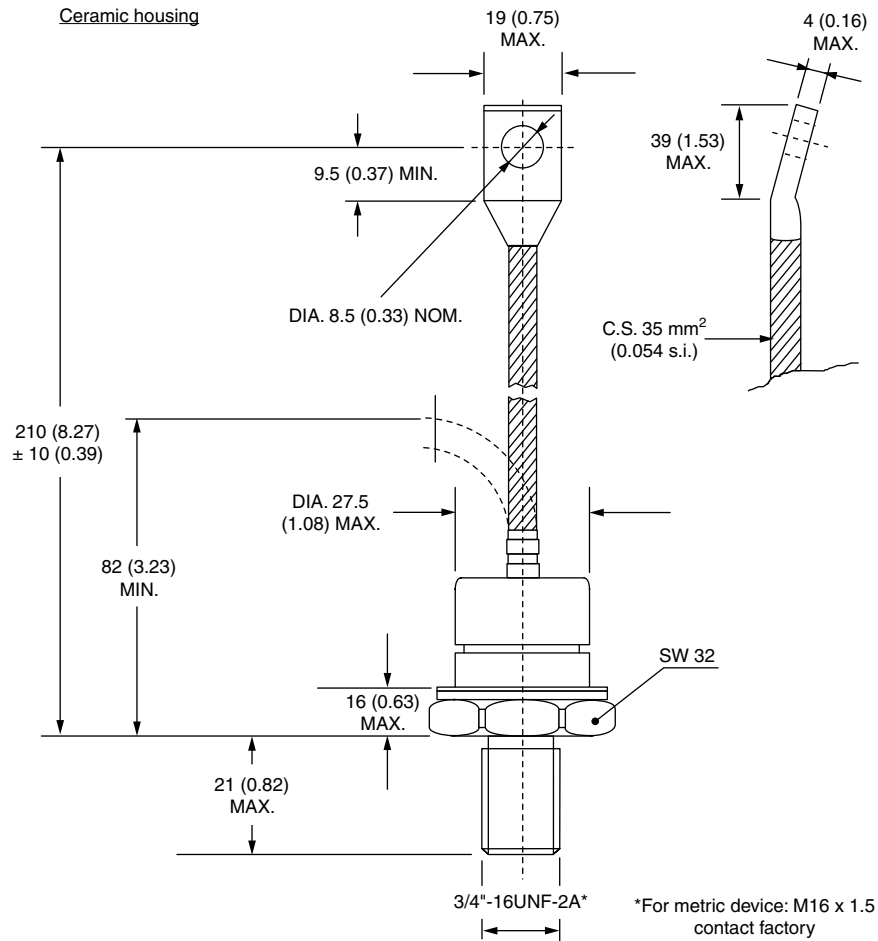
- 1** - Vishay semiconductors product
- 2** - Diode
- 3** - Essential part number
- 4** - 0 = standard recovery
- 5** -
 - N = stud normal polarity (cathode to stud)
 - R = stud reverse polarity (anode to stud)
- 6** - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 7** - P = stud base DO-205AB (DO-9) 3/4" 16UNF-2A
- 8** - C = ceramic housing

For metric device M16 x 1.5 contact factory

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95301

DO-205AB (DO-9)

DIMENSIONS in millimeters (inches)





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